



500V N-Channel MOSFET

Voltage

500 V

Current

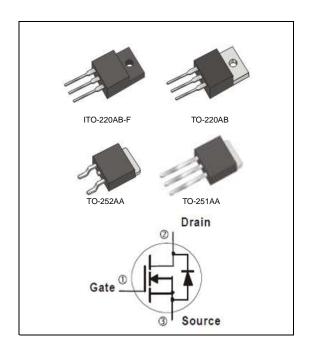
4 A

Features

- R_{DS(ON)}, V_{GS}@10V,I_D@2A<2.3Ω
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS2.0 (2011/65/EU & 2015/865/EU directive)
- Green molding compound as per IEC61249 Std..(Halogen Free)

Mechanical Data

Case: TO-251AA,TO-252AA,TO-220AB, ITO-220AB-F
Terminals: Solderable per MIL-STD-750, Method 2026



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	TO-251AA	TO-220AB	ITO-220AB-F	TO-252AA	UNITS
Drain-Source Voltage		V_{DS}	500				٧
Gate-Source Voltage		V_{GS}	<u>+</u> 30				V
Continuous Drain Current		I _D	4				Α
Pulsed Drain Current		I _{DM}	16				Α
Single Pulse Avalanche Energy (Note 1)		E _{AS}	125				mJ
Power Dissipation	T _C =25°C	P _D	78	90	42	78	W
	Derate above 25°C		0.62	0.72	0.34	0.62	W/°C
Operating Junction and		T_{J} , T_{STG}	-55~150				0.0
Storage Temperature Range							°C
Typical Thermal Resistance							
- Junction to Case		$R_{ heta JC}$	1.6	1.39	3.0	1.6	°C/W
- Junction to Ambient		$R_{ heta JA}$	110	62.5	120	110	

• Limited only By Maximum Junction Temperature





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static			•		•	
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =250uA	500	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250$ uA	2	3.0	4	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =2A	-	2.0	2.3	Ω
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =500V,V _{GS} =0V	-	-	1.0	uA
Gate-Source Leakage Current	I_{GSS}	$V_{GS}=\underline{+}30V, V_{DS}=0V$	1	-	<u>+</u> 100	nA
Diode Forward Voltage	V_{SD}	I _S =4A,V _{GS} =0V	-	0.8	1.4	V
Dynamic (Note 4)						
Total Gate Charge	Q_g	\/ 400\/ 1 44	-	9.8	-	nC
Gate-Source Charge	Q_gs	V_{DS} =400V, I_{D} =4A, V_{GS} =10V (Note 2,3)	-	2.2	-	
Gate-Drain Charge	Q_gd	V _{GS} =10V	-	3.9	-	
Input Capacitance	Ciss	\/	-	449	-	
Output Capacitance	V_{DS} =25V, V_{GS} =0V,		-	45	-	рF
Reverse Transfer Capacitance	Crss	f=1.0MHZ	1	13	-	
Turn-On Delay Time	td _(on)	(on)		12	-	
Turn-On Rise Time	t _r	$V_{DD}=250V, I_{D}=4A,$ $R_{G}=10\Omega$ (Note 2,3)	-	11	-	200
Turn-Off Delay Time	td _(off)	$R_{G}=10\Omega$ (total 2,8)		31	-	ns
Turn-Off Fall Time	t _f		-	7.6	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	ı		-	-	4	А
Diode Forward Current	I _S					
Maximum Pulsed Drain-Source				-	16	А
Diode Forward Current	I _{SM}		_			
Reverse Recovery Time	trr	V_{GS} =0V, I_{S} =4A	-	402	-	ns
Reverse Recovery Charge	Qrr	$dI_F/dt=100A/us^{(Note 2)}$	-	1.3	-	uC

NOTES:

- 1. L=10mH, I_{AS} =5A, V_{DD} =50V, R_{G} =25ohm, Starting T_{J} =25°C
- 2. Pulse width<300us, Duty cycle<2%
- 3. Essentially independent of operating temperature typical characteristics.
- 4. Guaranteed by design, not subject to production testing





TYPICAL CHARACTERISTIC CURVES

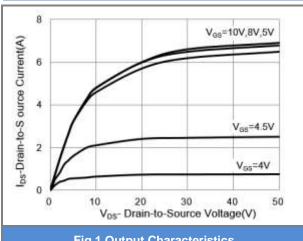


Fig.1 Output Characteristics

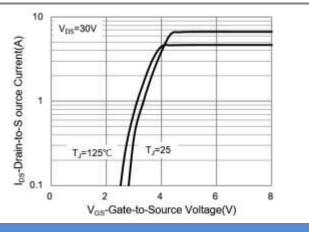


Fig.2 Transfer Characteristics

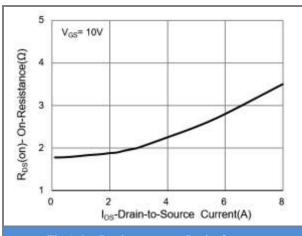


Fig.3 On-Resistance vs. Drain Current

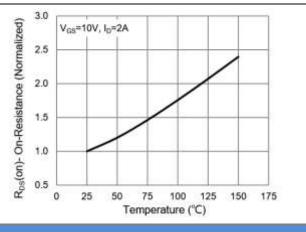
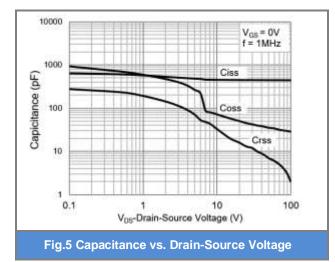


Fig.4 On-Resistance vs. Junction Temperature



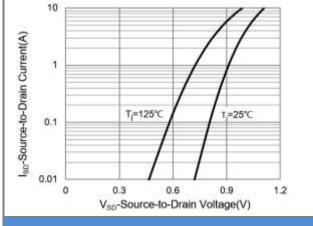


Fig.6 Source-Drain Diode Forward Voltage





TYPICAL CHARACTERISTIC CURVES

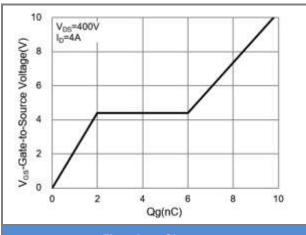


Fig.7 Gate Charge

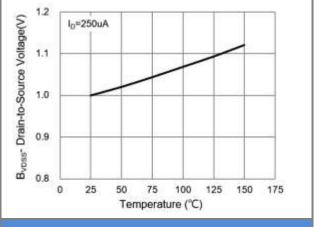


Fig.8 BV_{DSS} vs. Junction Temperature

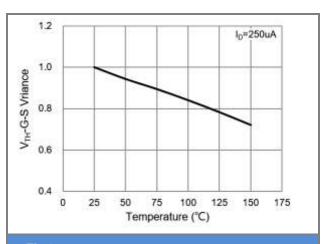


Fig.9 Threshold Voltage Variation with Temperature

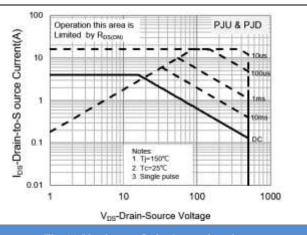


Fig.10 Maximum Safe Operating Area

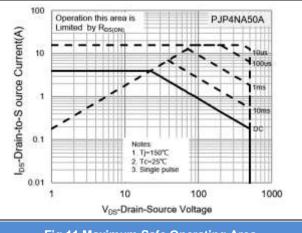


Fig.11 Maximum Safe Operating Area

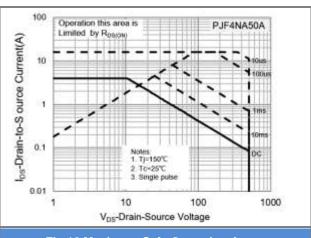


Fig.12 Maximum Safe Operating Area







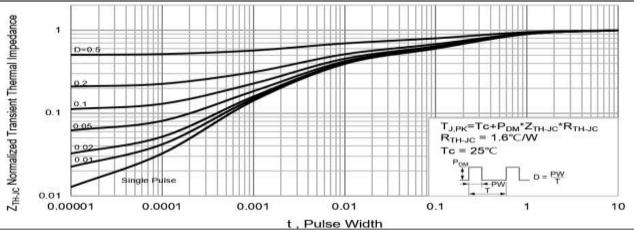


Fig.13 PJU/PJD Normalized Transient Thermal Impedance vs. Pulse Width

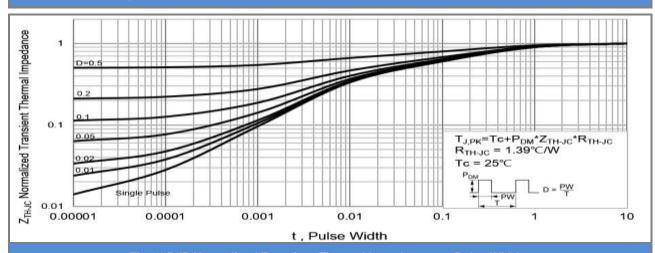


Fig.14 PJP Normalized Transient Thermal Impedance vs. Pulse Width

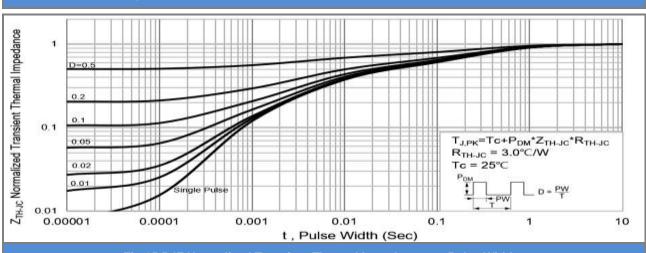
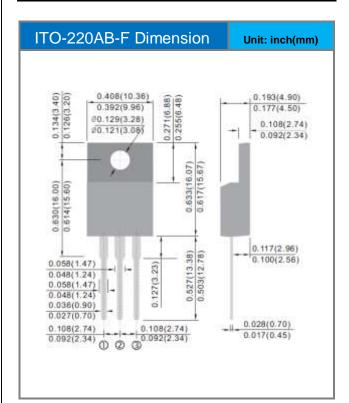


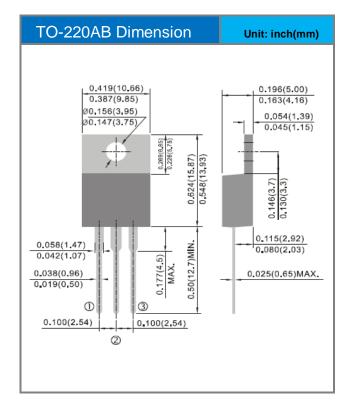
Fig.15 PJF Normalized Transient Thermal Impedance vs. Pulse Width

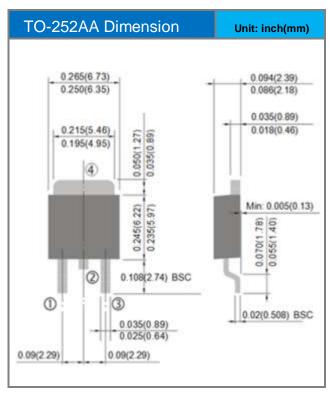


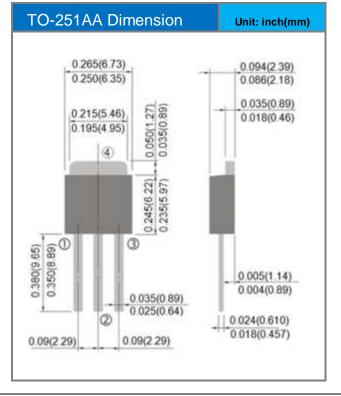


Packaging Information









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PJU4NA50A / PJD4NA50A / PJF4NA50A

PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJU4NA50A_T0_00001	TO-251AA	80pcs / Tube	U4NA50A	Halogen free
PJD4NA50A_L2_00001	TO-252AA	3,000pcs / 13" reel	D4NA50A	Halogen free
PJP4NA50A_T0_00001	TO-220AB	50pcs / Tube	P4NA50A	Halogen free
PJF4NA50A_T0_00001	ITO-220AB-F	50pcs / Tube	F4NA50A	Halogen free





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